

M54HC123

RAD-HARD DUAL RETRIGGERABLE MONOSTABLE MULTIVIBRATOR

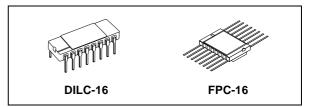
- HIGH SPEED: t_{PD} = 23 ns (TYP.) at V_{CC} = 6V
- LOW POWER DISSIPATION: STAND BY STATE: I_{CC}=4µA (MAX.) at T_A=25°C ACTIVE STATE: I_{CC}=200µA (MAX.) at V_{CC} = 5V
- HIGH NOISE IMMUNITY: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (MIN.)
- SYMMETRICAL OUTPUT IMPEDANCE:
 |I_{OH}| = I_{OL} = 4mA (MIN)
- BALANCED PROPAGATION DELAYS: t_{PLH} ≅ t_{PHL}
- WIDE OPERATING VOLTAGE RANGE: V_{CC} (OPR) = 2V to 6V
- WIDE OUTPUT PULSE WIDTH RANGE: t_{WOUT} = 120 ns ~ 60 s OVER AT V_{CC} = 4.5 V
- PIN AND FUNCTION COMPATIBLE WITH 54 SERIES 123
- SPACE GRADE-1: ESA SCC QUALIFIED
- 50 krad QUALIFIED, 100 krad AVAILABLE ON REQUEST
- NO SEL UNDER HIGH LET HEAVY IONS IRRADIATION
- DEVICE FULLY COMPLIANT WITH SCC-9207-006

DESCRIPTION

The M54HC123 is an high speed CMOS MONOSTABLE MULTIVIBRATOR fabricated with silicon gate C²MOS technology.

There are two trigger inputs, \overline{A} INPUT (negative edge) and B INPUT (positive edge). These inputs

PIN CONNECTION



ORDER CODES

PACKAGE	FM	EM
DILC	M54HC123D	M54HC123D1
FPC	M54HC123K	M54HC123K1

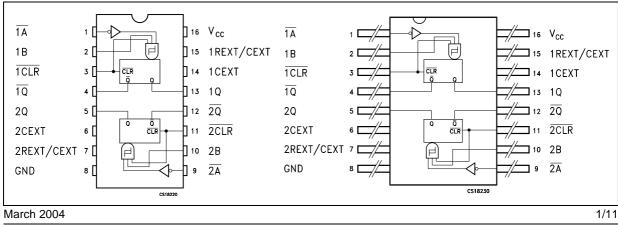
are valid for slow rising/falling signals, (tr=tf=l sec). <u>The</u> device may also be triggered by using the CLR input (positive-edge) because of the Schmitt-trigger input; after triggering the output maintains the MONOSTABLE state for the time period determined by the external resistor R_X and capacitor C_X. When C_X ≥ 10nF and R_X ≥ 10KΩ, the output pulse width value is approximately given by the formula: $t_{W(OUT)} = K \cdot C_x \cdot R_x$. (K \cong 0.45).

Taking $\overrightarrow{\text{CLR}}$ low breaks this MONOSTABLE STATE. If the next trigger pulse occurs during the MONOSTABLE period it makes the MONOSTABLE period longer. Limit for values of C_x and $R_x : C_x :$ NO LIMIT

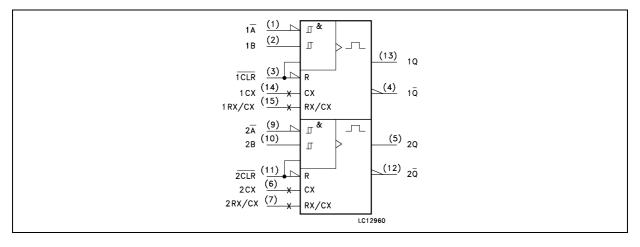
 $R_x : V_{CC} < 3.0V 5K\Omega$ to $1M\Omega$

 $V_{CC} \ge 3.0V \ 1K\Omega \text{ to } 1M\Omega$

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

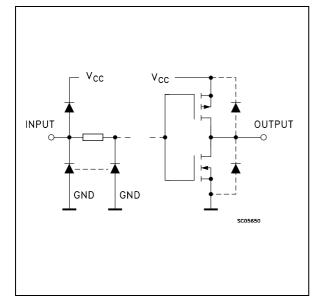


IEC LOGIC SYMBOLS



PIN DESCRIPTION

INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN N°	SYMBOL	NAME AND FUNCTION
1,9	1 A , 2 A	Trigger Inputs (Negative Edge Triggered)
2, 10	1B, 2B	Trigger Inputs (Positive Edge Triggered)
3, 11	1 <u>CLR</u> 2 CLR	Direct Reset LOW and trigger Action at Positive Edge
4, 12	1 <u>Q</u> , 2 <u>Q</u>	Outputs (Active Low)
7	2R _X /C _X	External Resistor Capacitor Connection
13, 5	1Q, 2Q	Outputs (Active High)
14, 6	1C _X 2C _X	External Capacitor Connection
15	1R _X /C _X	External Resistor Capacitor Connection
8	GND	Ground (0V)
16	V _{CC}	Positive Supply Voltage

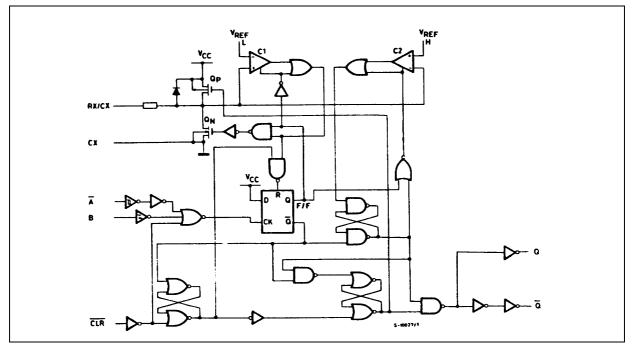
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TRUTH TABLE

	INPUTS		OUTI	PUTS	Note
Ā	В	CLR	Q	Q	NOTE
	Н	Н			OUTPUT ENABLE
Х	L	Н	L	Н	INHIBIT
Н	Х	Н	L	Н	INHIBIT
L		Н			OUTPUT ENABLE
L	Н				OUTPUT ENABLE
Х	Х	L	L	Н	INHIBIT

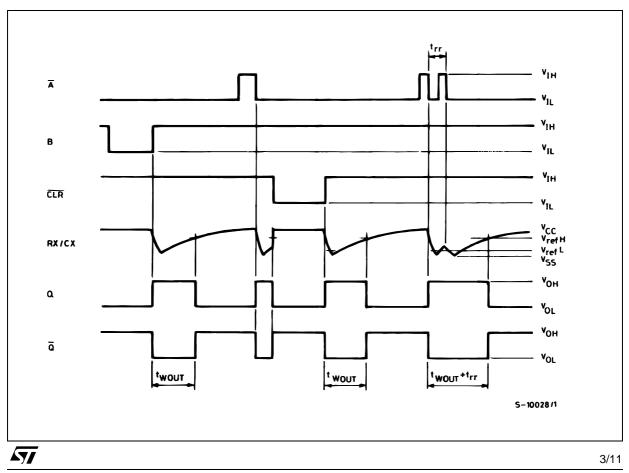
X : Don't Care

SYSTEM DIAGRAM

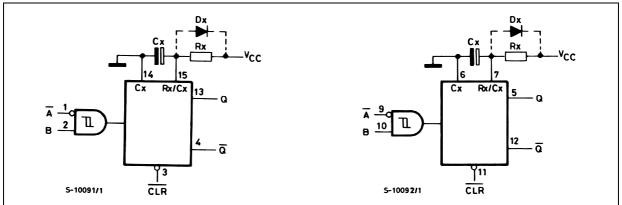


This logic diagram has not be used to estimate propagation delays

TIMING CHART



BLOCK DIAGRAM



 (1) Cx, Rx, Dx are external components.
 (2) Dx is a clamping diode.
 The external capacitor is charged to Vcc in the stand-by-state, i.e. no trigger. When the supply voltage is turned off Cx is discharged mainly the external capacitor is charged to Vcc in the stand-by-state, i.e. no trigger. trough an internal parasitic diode (see figures). If Cx is sufficiently large and Vcc decreases rapidly, there will be some possibility of damaging the I.C. with a surge current or latch-up. If the voltage supply filter capacitor is large enough and Vcc decrease slowly, the surge current is automatically limited and damage to the I.C. is avoided. The maximum forward current of the parasitic diode is approximately 20 mA. In cases where Cx is large the time taken for the supply voltage to fall to 0.4 Vcc can be calculated as follows:

 $t_1 \ge (Vcc - 0.7) \times Cx/20mA$ In cases where t_1 is too short an external clamping diode is required to protect the I.C. from the surge current.

FUNCTIONAL DESCRIPTION

STAND-BY STATE

The external capacitor, Cx, is fully charged to V_{CC} in the stand-by state. Hence, before triggering, transistor Qp and Qn (connected to the Rx/Cx node) are both turned-off. The two comparators that control the timing and the two reference voltage sources stop operating. The total supply current is therefore only leakage current.

TRIGGER OPERATION

Triggering occurs when:

1 st) A is "LOW" and B has a falling edge;

2 nd) B is "HIGH" and A has a rising edge;

3 rd) A is "LOW" and B is HIGH and C1 has a rising edge;

After the multivibrator has been retriggered comparator C1 and C2 start operating and Qn is turned on. Cx then discharges through Qn. The voltage at the node R/C external falls.

When it reaches V_{REFL} the output of comparator C1 becomes low. This in turn reset the flip-flop and Qn is turned off.

At this point C1 stops functioning but C2 continues to operate.

The voltage at R/C external begins to rise with a time constant set by the external components Rx, Cx.

Triggering the multivibrator causes Q to go high after internal delay due to the flip-flop and the gate. Q remains high until the voltage at R/C external rises again to V_{REFH}. At this point C2 output goes low and O goes low. C2 stop operating. That means that after triggering when the voltage R/C external returns to V_{RFFH} the multivibrator has returned to its MONOSTABLE STATE. In the case where $Rx \cdot Cx$ are large enough and the discharge time of the capacitor and the delay time in the I.C. can be ignored, the width of the output pulse $t_{w(out)}$ is as follows:

$$t_{W(OUT)} = 0.45 \text{ Cx} \cdot \text{Rx}$$

RE - TRIGGERED OPERATION

When a second trigger pulse follows the first its effect will depend on the state of the multivibrator. If the capacitor Cx is being charged the voltage level of R/C external falls to V_{RFFI} again and Q remains High i.e. the retrigger pulse arrives in a time shorter than the period $Rx \cdot Cx$ seconds, the capacitor charging time constant. If the second trigger pulse is very close to the initial trigger pulse it is ineffective; i.e. the second trigger must arrive in the capacitor discharge cycle to be ineffective; Hence the minimum time for a second trigger to be effective depends on V_{CC} and Cx

RESET OPERATION

CL is normally high. If CL is low, the trigger is not effective because Q output goes low and trigger control flip-flop is reset.

Also transistor Op is turned on and Cx is charged quickly to V_{CC} . This means if C_L input goes low the IC becomes waiting state both in operating and non operating state.

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7	V
VI	DC Input Voltage	-0.5 to V _{CC} + 0.5	V
Vo	DC Output Voltage	-0.5 to V _{CC} + 0.5	V
Ι _{ΙΚ}	DC Input Diode Current	± 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
Ι _Ο	DC Output Current	± 25	mA
I_{CC} or I_{GND}	DC V _{CC} or Ground Current	± 50	mA
PD	Power Dissipation	300	mW
T _{stg}	Storage Temperature	-65 to +150	°C
ΤL	Lead Temperature (10 sec)	265	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V _{CC}	Supply Voltage		2 to 6	V
VI	Input Voltage	0 to V _{CC}	V	
Vo	Output Voltage		0 to V _{CC}	V
T _{op}	Operating Temperature		-55 to 125	°C
	Input Rise and Fall Time	$V_{CC} = 2.0V$	0 to 1000	ns
t _r , t _f		$V_{CC} = 4.5V$	0 to 500	ns
		$V_{CC} = 6.0V$	0 to 400	ns
Cx	External Capacitor		NO LIMITATION	pF
Рv	External Resistor	V _{CC} < 3V	5K to 1M	Ω
Rx		$V_{CC} \ge 3V$	1K to 1M	

The Maximum allowable values of Cx and Rx are a function of leakage of capacitor Cx, the leakage of device and leakage due to the board layout and surface resistance. Susceptibility to externally induced noise may occur for $Rx > 1M\Omega$

DC SPECIFICATIONS

		Т	Test Condition		Value						
Symbol Parameter		V _{CC} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		Unit
	Min.		Тур.	Max.	Min.	Max.	Min.	Max.			
VIH	VIH High Level Input	2.0		1.5			1.5		1.5		
	Voltage	4.5		3.15			3.15		3.15		V
		6.0		4.2			4.2		4.2		
V _{IL}	Low Level Input Voltage	2.0				0.5		0.5		0.5	
		4.5				1.35		1.35		1.35	V
		6.0				1.8		1.8		1.8	

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		Test Condition		Value								
Symbol	Parameter	V _{CC}		т	T _A = 25°C			85°C	-55 to 125°C		Unit	
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.		
V _{OH} High Level Output Voltage	High Level Output	2.0	I _O =-20 μA	1.9	2.0		1.9		1.9			
	Voltage	4.5	I _O =-20 μA	4.4	4.5		4.4		4.4			
		6.0	I _O =-20 μA	5.9	6.0		5.9		5.9		V	
		4.5	I _O =-4.0 mA	4.18	4.31		4.13		4.10			
		6.0	I _O =-5.2 mA	5.68	5.8		5.63		5.60			
OL	Low Level Output Voltage	2.0	I _O =20 μA		0.0	0.1		0.1		0.1		
		4.5	I _O =20 μA		0.0	0.1		0.1		0.1		
		6.0	I _O =20 μA		0.0	0.1		0.1		0.1	V	
		4.5	I _O =4.0 mA		0.17	0.26		0.33		0.40		
		6.0	I _O =5.2 mA		0.18	0.26		0.33		0.40		
Ι _Ι	Input Leakage Current	6.0	$V_{I} = V_{CC} \text{ or } GND$			± 0.1		± 1		± 1	μA	
I _{CC}	Quiescent Supply Current	6.0	$V_{I} = V_{CC}$ or GND			4		40		80	μA	
I _{CC'}	Active State Supply	2.0	$V_{I} = V_{CC} \text{ or } GND$		45	200		260		320	μA	
	Current (1)		Pin 7 or 15		500	600		780		960	μΑ	
1) : Per Circ		6.0	$V_{IN} = V_{CC}/2$		0.7	1		1.3		1.6	mA	

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		Tes	t Condition				Value				
Symbol	Parameter	V _{CC}		T _A = 25°C		-40 to	⊳ 85°C	-55 to 125°C		Uni	
		(Ŭ)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
t _{TLH} t _{THL} Output Transition	Output Transition Time	2.0			30	75		95		110	
		4.5	-		8	15		19		22	ns
		6.0	-		7	13		16		19	
t _{PLH} t _{PHL}	Propagation Delay Time	2.0			102	210		265		315	
	(Ā, B - Q, Q)	4.5	-		29	42		53		63	ns
		6.0	-		22	36		45		54	
t _{PLH} t _{PHL}	Propagation Delay Time	2.0			102	235		295		355	
	(CLR TRIGGER - Q, Q)	4.5	-		31	47		59		71	ns
		6.0	-		23	40		50		60	
t _{PLH} t _{PHL}	Propagation Delay Time	2.0			68	160		200		240	
(CLR - Q, Q)	$(\overline{\text{CLR}} - \overline{\text{Q}}, \overline{\text{Q}})$	4.5	-		20	32		40		48	ns
		6.0	-		16	27		34		41	
t _{WOUT} Output Pulse Wic	Output Pulse Width	2.0	0 400 E		1.4						
		4.5	Cx = 100 pF Rx = 10KΩ		1.2						μs
		6.0	10002		1.1						
		2.0	0.045		4.6						
		4.5	Cx = 0.1μF Rx = 100KΩ		4.4						ms
		6.0	1001022		4.3						
Δt_{WOUT}	Output Pulse Width Error Between Circuits in Same Package				±1						%
t _{W(H)}	Minimum Pulse Width	2.0				75		95		110	
t _{W(L)}		4.5	-			15		19		22	ns
		6.0	-			13		16		19	
t _{W(L)}	Minimum Pulse Width	2.0				75		95		110	
()	(CLR)	4.5	-			15		19		22	ns
		6.0	-			13		16		19	
t _{rr}	Minimum Retrigger Time	2.0	o 100 F		325						
		4.5	Cx = 100 pF Rx = 10KΩ		108						ns
		6.0	1X = 10X2		78						1
		2.0	0 0 0		5						
		4.5	Cx = 0.1μF Rx = 100KΩ		1.4						μs
		6.0	1X = 100X22		1.2						

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ns}$)

CAPACITIVE CHARACTERISTICS

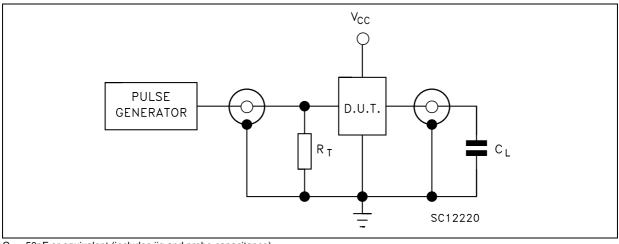
		Test Condition		Value							
Symbol Parameter	V _{cc} (V)	T _A = 25°C			-40 to 85°C		-55 to 125°C		Unit		
		Min.	Тур.	Max.	Min.	Max.	Min.	Max.			
C _{IN}	Input Capacitance	5.0			5	10		10		10	pF
C _{PD}	Power Dissipation Capacitance (note 1)	5.0			162						pF

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$ ' Duty/100 + Ic/2(per monostable) (I_{cc} ': Active Supply current) (Duty:%)



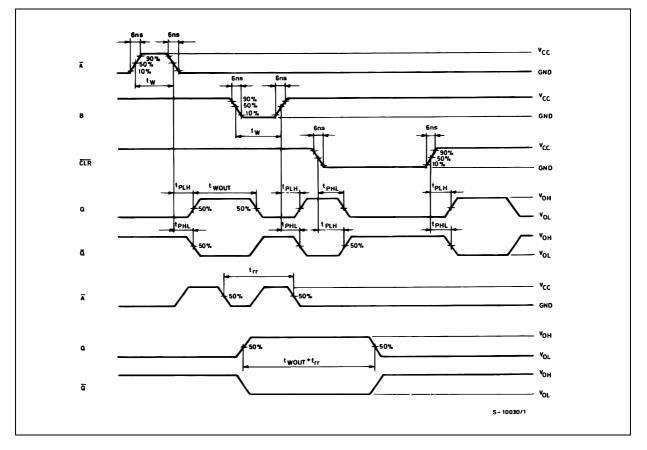
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TEST CIRCUIT



 C_L = 50pF or equivalent (includes jig and probe capacitance) R_T = Z_{OUT} of pulse generator (typically 50 Ω)

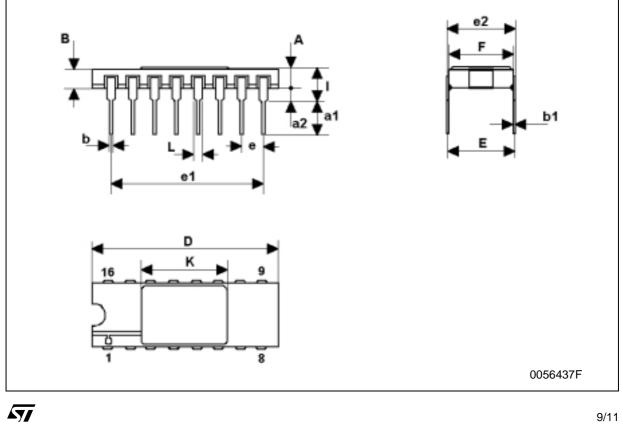
WAVEFORM: SWITCHING CHARACTERISTICS TEST WAVEFORM (f=1MHz; 50% duty cycle)



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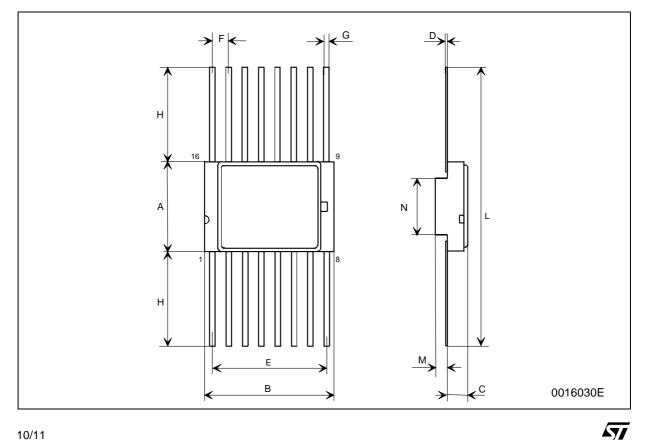
DIM		mm.		inch					
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.			
А	2.1		2.71	0.083		0.107			
a1	3.00		3.70	0.118		0.146			
a2	0.63	0.88	1.14	0.025	0.035	0.045			
В	1.82		2.39	0.072		0.094			
b	0.40	0.45	0.50	0.016	0.018	0.020			
b1	0.20	0.254	0.30	0.008	0.010	0.012			
D	20.06	20.32	20.58	0.790	0.800	0.810			
е	7.36	7.62	7.87	0.290	0.300	0.310			
e1		2.54			0.100				
e2	17.65	17.78	17.90	0.695	0.700	0.705			
e3	7.62	7.87	8.12	0.300	0.310	0.320			
F	7.29	7.49	7.70	0.287	0.295	0.303			
I			3.83			0.151			
К	10.90		12.1	0.429		0.476			
L	1.14		1.5	0.045		0.059			

DILC-16 MECHANICAL DATA



	FPC-16 MECHANICAL DATA										
DIM.		mm.			inch						
Diwi.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.					
А	6.75	6.91	7.06	0.266	0.272	0.278					
В	9.76	9.94	10.14	0.384	0.392	0.399					
С	1.49		1.95	0.059		0.077					
D	0.102	0.127	0.152	0.004	0.005	0.006					
E	8.76	8.89	9.01	0.345	0.350	0.355					
F		1.27			0.050						
G	0.38	0.43	0.48	0.015	0.017	0.019					
Н	6.0			0.237							
L	18.75		22.0	0.738		0.867					
М	0.33	0.38	0.43	0.013	0.015	0.017					
Ν		4.31			0.170						

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